

KBP5005-KBP510/G

Single Phase 5.0Amp Glass passivated Bridge Rectifiers

Features

Rating to 1000V PRV

· Idea for printed circuit board

Reliable low cost construction utilizing molded plastic technique

 The plastic material has UL flammability classification 94V-0

 The G suffix is uses for photoresist chip, otherwise it is a knife scraping chip

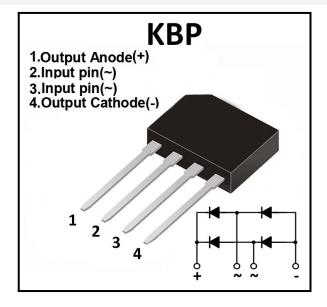
MECHANICAL DATA

Polarity: As marked on body

· Weight: 0.05 ounces, 1.52 grams

• Mounting position : Any

Mechanical Data



Maximum Ratings And Electrical Characteristics (@ T_A =25°C unless otherwise noted)

Symbol	Parameter	KBP 5005G	KBP 501G	KBP 502G	KBP 504G	KBP 506G	KBP 508G	KBP 510G	Unit
V _{RRM}	Maximum repetitive peak reverse voltage	50	100	200	400	600	800	1000	V
V _{RMS}	Maximum RMS voltage	35	70	140	280	420	560	700	V
V _{DC}	Maximum DC blocking voltage	50	100	200	400	600	800	1000	V
I _{AV}	Maximum Average Forward (With heatsink)	5.0							А
	RectifiedCurrent @T _C =105°C(Without heatsink)	2.5							
	Peak Forward Surge Current @T _j =25°C	150						Α	
I _{FSM}	8.3ms single half sine-wave @T _j =125°C	120							
V_{F}	Maximum forward voltage at 4.0A DC	1.10					V		
	Maximum DC reverse current @T _J =25°C	5.0						uA	
I _R	at rated DC blocking voltage @ T _J =125°C	500							
I _t ²	I _t ² Rating for fusing (3ms≤t≤8.3ms)	59.76			A _S ²				
CJ	Typical junction capacitance (Note 1)	46				pF			
	Typical thermal resistance(Unit mounted on	3.0						°C/W	
$R_{\theta JC}$	75mmx75mmx1.6mm Copper plate heatsink.)								
R _{θJC}	Typical thermal resistance(without heatsink)	8.0			°C/W				
T _J , T _{STG}	Operation and Storage Temperature Range	-55 to +150			°C				

Note:(1)Measured at 1MHz and applied reverse voltage of 4.0V D.C.







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Ratings And Characteristic Curves

Figure 1: FORWARD CURRENT DERATING CURVE

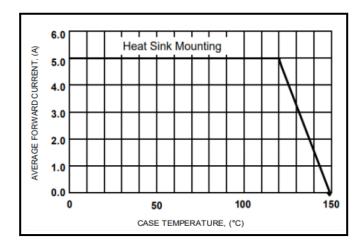


Figure 3:TYPICAL JUNCTION CAPACITANCE

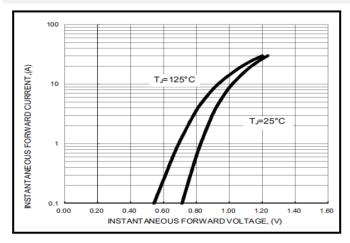


Figure 5:TYPICAL REVERSE CHARACTERISTICS

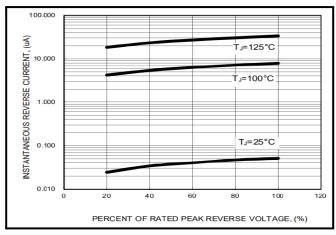


Figure 2: MAXIMUM NON-REPETITIVE SURGE CUR-

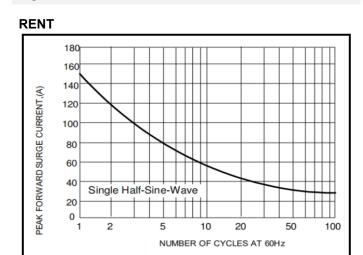
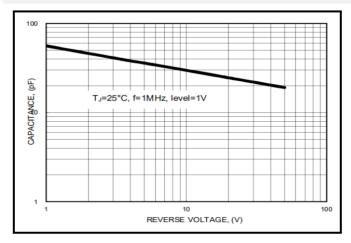


Figure 4:TYPICAL FORWARD CHARACTERISTICS



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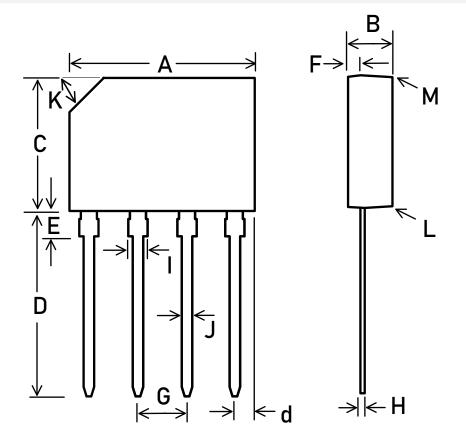




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Outline Drawing - KBP



SYMBOL	MILLIMETER					
SYMBOL	MIN.	MAX.				
А	14.2	14.7				
В	3.30	3.60				
С	10.2	10.6				
D	13.8	14.4				
d	1.40	1.70				
E	1.80	2.20				
F	0.80	1.10				
G	3.71	3.91				
Н	0.30	0.55				
ı	1.22	1.42				
J	0.76	0.86				
K	2.7 x 45°					
L	_	3°				
М	_	2 °				